## NSN 5961-01-464-9100

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-464-9100 **Inclosure Material:** Plastic **Overall Length:** Between 0.776 millimeters and 0.799 millimeters **End Application:** C130 pwr unit **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 repetitive peak reverse voltage and 1.8 forward voltage, dc **Current Rating Per Characteristic:** 500.00 microamperes forward current, average peak and 14.00 milliamperes forward current, average major and 100.00 amperes forward current, average preset and 60.00 amperes source cutoff current preset **Special Features:** Max operating temp 150 degrees celcius **Terminal Type And Quantity:** 3 insulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0